## NSN 5962-01-431-4612

Memory Microcircuit - Page 1 of 1



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Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
Pacer dawn
Features Provided:
Electrostatic sensitive and hermetically sealed and monolithic and radiation hardened
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Complementary-metal oxide-semiconductor logic
Criticality Code Justification:
Cbbl
Case Outline Source And Designator:
D-7 mil-m-38510
Product Name:
Microcircuit, digital, cmos, 16kx4 bit static ram, monolithic silicon
Voltage Rating And Type Per Characteristic:
-0.3 volts total supply and 7.0 volts total supply
Memory Device Type:
Ram
Terminal Type And Quantity:
22 printed circuit
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A458a0